## NEUROMORPHIC **COMPUTING SYSTEMS BASED ON MEMRISTIVE**

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## DEVICES

## ABSTRACT

Deep Neural Networks (DNN) are widely used for many artificial intelligence applications with great success. However, they often come with high computation cost and complexity. Accelerators are crucial in improving energy efficiency and throughput, particularly for embedded Al applications. Resistive random-access memory (RRAM), a form of memristive device or memristor, has the potential to enable efficient AI accelerator implementation, as the weights can be mapped as the conductance values of RRAM devices and computation can be directly performed in-memory. Specifically, by converting input activations into voltage pulses, vector-matrix multiplications (VMM) can be performed in analog domain, in place and in parallel, thus achieving high energy efficiency during

System performance metrics including throughput and energy efficiency will be discussed based on analyzing standard DNN models such as VGG-16 and MobileNet. Challenges such as quantization effects, finite array size, and device non-idealities will also be analyzed. Beyond DNNs, the internal dynamics of RRAM devices can be used to natively process temporal data, e.g. performing time series analysis, in the form of reservoir computing systems and 2nd-order memristor networks. Examples of such systems will be discussed, including the potential for efficient bio-electronic interfaces.

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operation.

In this presentation, I will first introduce prototype computing systems based on such memristive devices, then discuss how practical DNN models can be mapped onto realistic RRAM arrays in a modular design.

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